NSN 5961-01-089-8863

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View Online at https://aerobasegroup.com/nsn/5961-01-089-8863 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 2.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads coating gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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